

■ INTRODUCTION

The CE8808 Series is a series of high-precision voltage detectors developed using CMOS process. The detection voltage is fixed internally, with an accuracy of 2.0%. Two output forms, NMOS open-drain and CMOS output, are available.

■ FEATURES

- Ultra-low current consumption: 0.9μA@3.5V(Typ.)
- High-precision detection voltage:±2.0%
- Operating voltage range:0.95 V~ 7.0V
- Hysteresis characteristics: -V<sub>DET</sub>×5% (Typ.)
- Detection voltage: 1.5V ~ 6.0V(10mV step)
- Output forms:  
NMOS open-drain output (Active Low)  
CMOS output (Active Low)

■ APPLICATIONS

- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection
- Power monitor for portable equipment such as notebook computers, digital cameras, PDA, and cellular phones.
- Constant voltage power monitors for cameras, video equipment and communication devices.
- Power monitor for microcomputers and reset for CPUs.

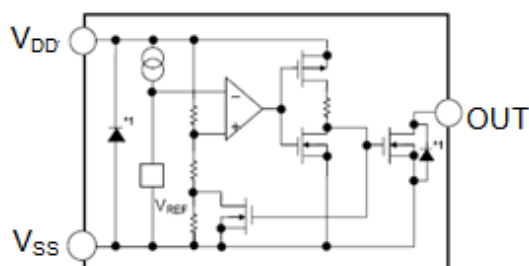
■ ORDER INFORMATION

CE8808①②③④⑤

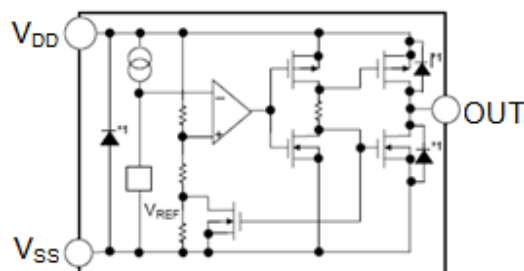
DESIGNATOR	SYMBOL	DESCRIPTION
①	C	CMOS
	N	NMOS open drain
②③④	Integer	Detection Voltage (1.50V~6.00V), “④”elide when it is “0” e.g. 3.0V=②:3, ③:0 2.93V=②:2, ③:9, ④:3
⑤	M/MA/MB/MR	Package: SOT-23,SOT-23-3/5
	N	Package: SOT-343(SC-82)
	P	Package: SOT-89-3
	T/TA	Package: TO-92

■ BLOCK DIAGRAMS

NMOS open-drain

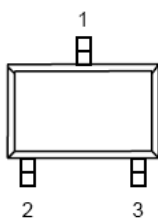


CMOS output



■ PIN CONFIGURATION

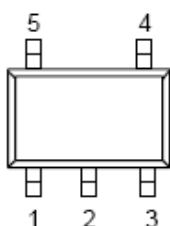
SOT-23-3  
Top view



CE8808 Series (SOT-23-3/SOT-23)

PIN NO.	M	MA	MB	FUNCTION
1	V <sub>DD</sub>	V <sub>DD</sub>	V <sub>DD</sub>	Voltage input pin
2	V <sub>OUT</sub>	-	V <sub>OUT</sub>	Voltage detection output pin
	-	V <sub>SS</sub>	-	Ground
3	V <sub>SS</sub>	-	V <sub>SS</sub>	Ground
	-	V <sub>OUT</sub>	-	Voltage detection output pin

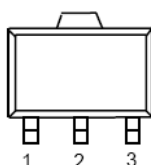
SOT-23-5  
Top view



CE8808 Series (SOT-23-5)

PIN NO.	MR	FUNCTION
1	V <sub>OUT</sub>	Voltage detection output pin
2	V <sub>DD</sub>	Voltage input pin
3	V <sub>SS</sub>	Ground
4	NC	No connection
5	NC	No connection

SOT-89-3  
Top view



CE8808 Series (SOT-89-3)

PIN NO.	P	FUNCTION
1	V <sub>OUT</sub>	Voltage detection output pin
2	V <sub>DD</sub>	Voltage input pin
3	V <sub>SS</sub>	Ground

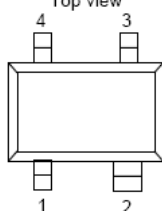
CE8808 Series (TO-92)

TO-92  
Bottom view



PIN NO.	T	TA	FUNCTION
1	V <sub>OUT</sub>	-	Voltage detection output pin
	-	V <sub>DD</sub>	Voltage input pin
2	V <sub>DD</sub>	-	Voltage input pin
	-	V <sub>SS</sub>	Ground
3	V <sub>SS</sub>	-	Ground
	-	V <sub>OUT</sub>	Voltage detection output pin

SOT343(SC-82)  
Top view



CE8808 Series (SOT343)

PIN NO.	N	FUNCTION
1	V <sub>OUT</sub>	Voltage detection output pin
2	V <sub>DD</sub>	Voltage input pin
3	NC	No Connection
4	V <sub>SS</sub>	Ground

## ■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNITS
Power supply voltage		$V_{DD}$	$V_{SS}-0.3 \sim V_{SS}+8$	V
Output voltage		$V_{OUT}$	$V_{SS}-0.3 \sim V_{SS}+8$	V
Power dissipation	SOT-23-3	PD	250	mW
	SOT-89		500	mW
	TO-92		500	mW
	SOT343		250	mW
Operating ambient temperature		$T_{opr}$	-40 ~ +85	°C
Storage temperature		$T_{stg}$	-40 ~ +125	°C
Soldering Temperature & Time		$T_{solder}$	260°C, 10s	

## ■ ELECTRICAL CHARACTERISTICS

(Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Detection voltage*1	$-V_{DET}$	—		$-V_{DET(S)} \times 0.98$	$-V_{DET(S)}$	$-V_{DET(S)} \times 1.02$	V
Hysteresis width	$V_{HYS}$	—		$0.02 \times -V_{DET(S)}$	$0.05 \times -V_{DET(S)}$	$0.08 \times -V_{DET(S)}$	V
Current consumption	$I_{SS}$	$V_{DD} = -V_{DET} + 0.5V$	CE8808C/N20~26	—	1.0	2.0	uA
			CE8808C/N 26~39	—	1.2	2.5	uA
			CE8808C/N 39~60	—	1.5	3.0	uA
Operating voltage	$V_{DD}$	—		0.95	—	7	V
Output current	$I_{OUT}$	NMOS: $V_{OUT} = 0.5V$ $V_{DD} = -V_{DET} - 0.5V$	CE8808C/N 20~26	3.0	13.0	—	mA
			CE8808C/N 26~39	3.0	15.0	—	mA
			CE8808C/N 39~60	3.0	18.0	—	mA
		PMOS: $V_{DD} - V_{OUT} = 0.5V$ $V_{DD} = -V_{DET} + 0.5V$	CE8808C/N 20~26	1.5	4.0	—	mA
			CE8808C/N 26~39	1.5	6.0	—	mA
			CE8808C/N 39~60	1.5	8.0	—	mA
Leakage current	$I_{LEAK}$	Only for NMOS open-drain output products, $V_{DD} = 8.0V, V_{OUT} = 8.0V$		—	—	1.0	uA
temperature coefficient		Ta=-40°C ~+85°C		—	±120	±360	ppm/°C
Delay time	$T_{PLH}$				200		us

\*1. -VDET: Actual detection voltage value, -VDET(S): Specified detection voltage value

## ■ FUNCTIONAL DESCRIPTION

1. When a voltage higher than the release voltage ( $+V_{DET}$ ) is applied to the voltage input pin ( $V_{DD}$ ), the voltage will gradually fall. When a voltage higher than the detect voltage ( $-V_{DET}$ ) is applied to  $V_{DD}$ , output ( $V_{OUT}$ ) will be equal to the input at  $V_{DD}$ .

Note that high impedance exists at  $V_{OUT}$  with the N-channel open drain configuration. If the pin is pulled up,  $V_{OUT}$  will be equal to the pull up voltage.

2. When  $V_{DD}$  falls below  $-V_{DET}$ ,  $V_{OUT}$  will be equal to the ground voltage ( $V_{SS}$ ) level (detect state).

Note that this also applies to N-channel open drain configurations.

3. When  $V_{DD}$  falls to a level below that of the minimum operating voltage ( $V_{MIN}$ ) output will become unstable.

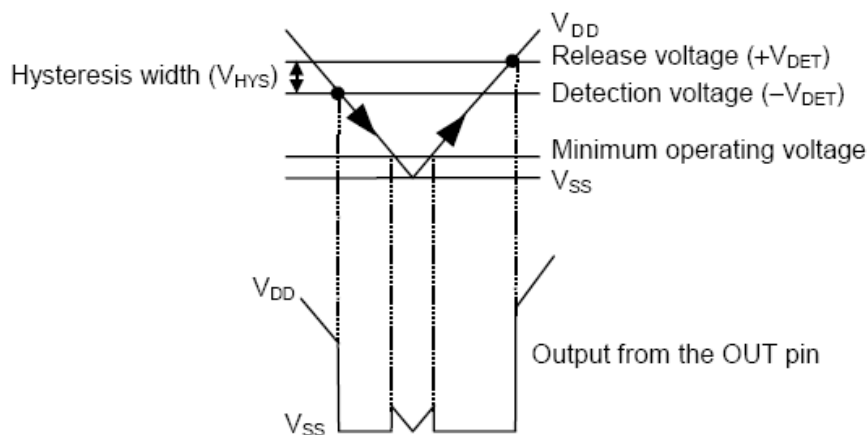
Because the output pin is generally pulled up with N-channel open drain configurations, output will be equal to pull up voltage.

4. When  $V_{DD}$  rises above the  $V_{SS}$  level (excepting levels lower than minimum operating voltage),  $V_{OUT}$  will be equal to  $V_{SS}$  until  $V_{DD}$  reaches the  $+V_{DET}$  level.

5. Although  $V_{DD}$  will rise to a level higher than  $+V_{DET}$ ,  $V_{OUT}$  maintains ground voltage level via the delay circuit.

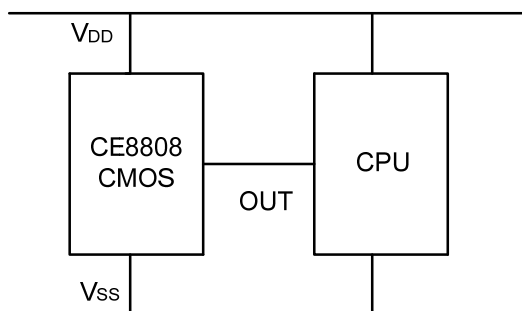
6. Following transient delay time,  $V_{DD}$  will be output at  $V_{OUT}$ .

Note that high impedance exists with the N-channel open drain configuration and that voltage will be dependent on pull up.

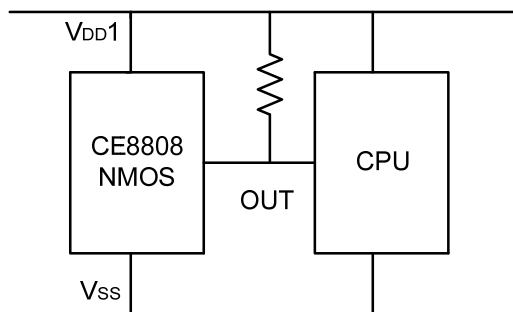
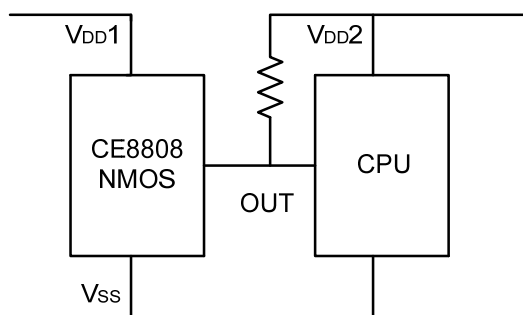


■ TYPICAL APPLICATION CIRCUITS

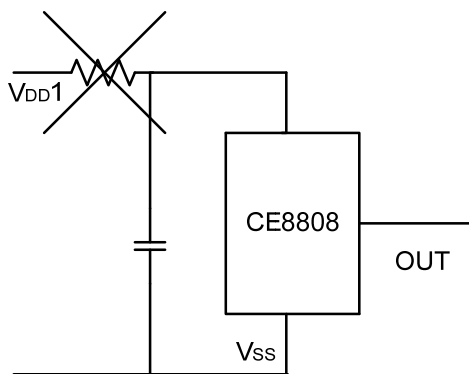
1、CMOS output:



2、NMOS open-drain

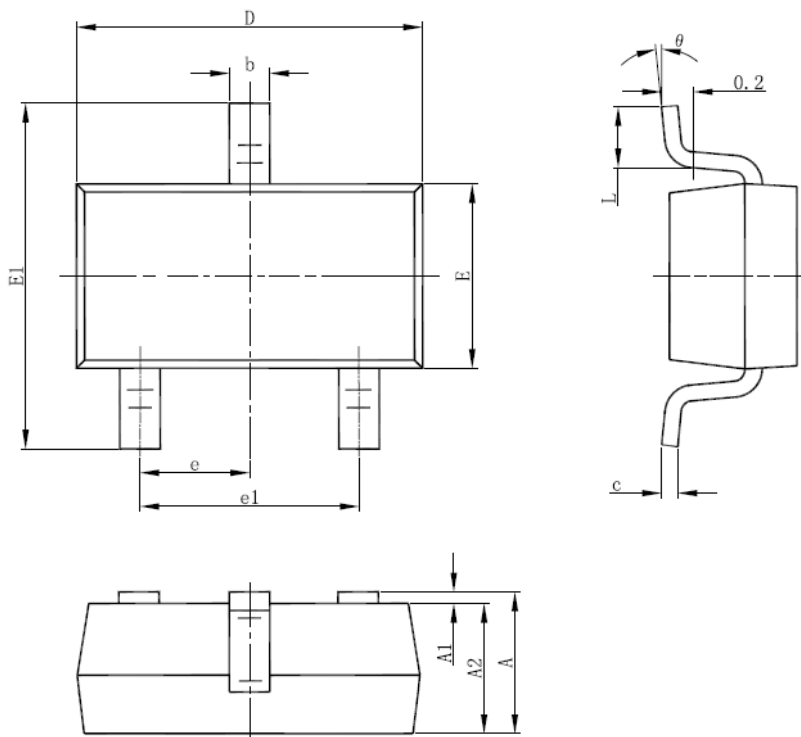


3. Forbidden Circuits



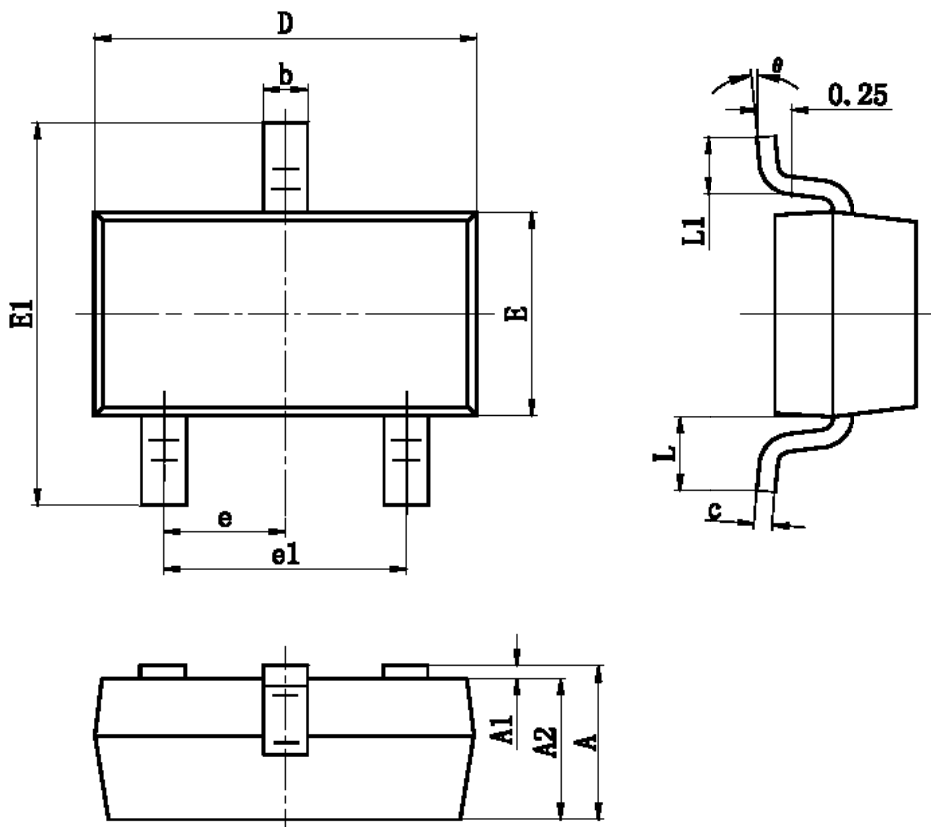
■ PACKAGING INFORMATION

- SOT-23-3



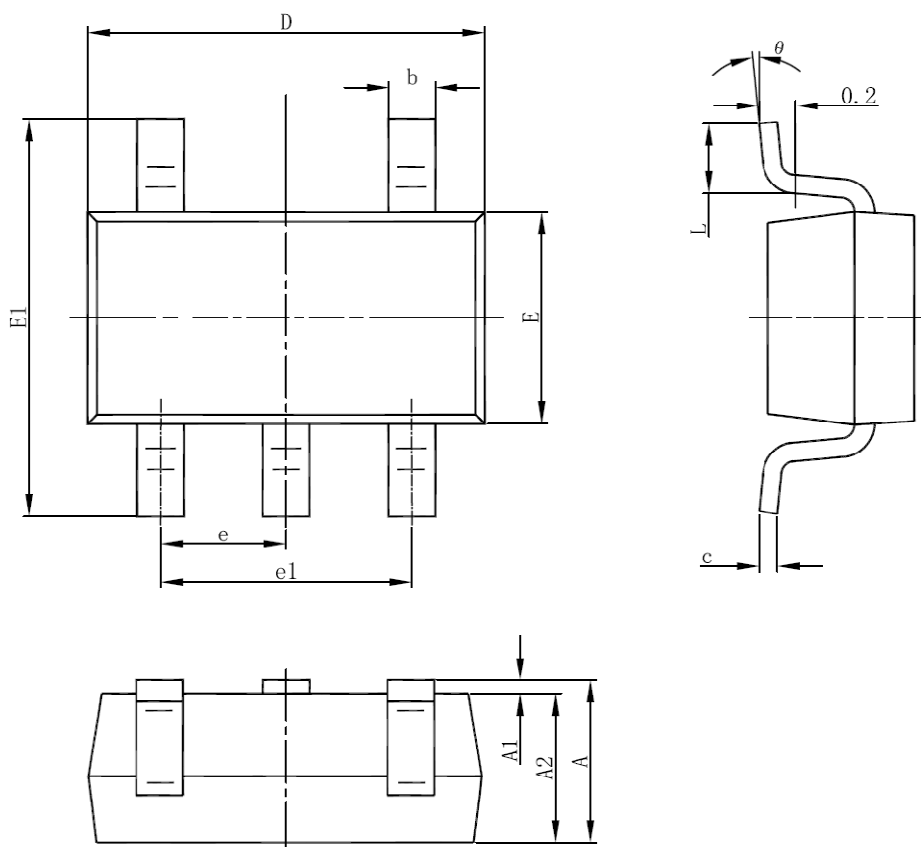
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
$\theta$	0°	8°	0°	8°

• SOT-23



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	6°

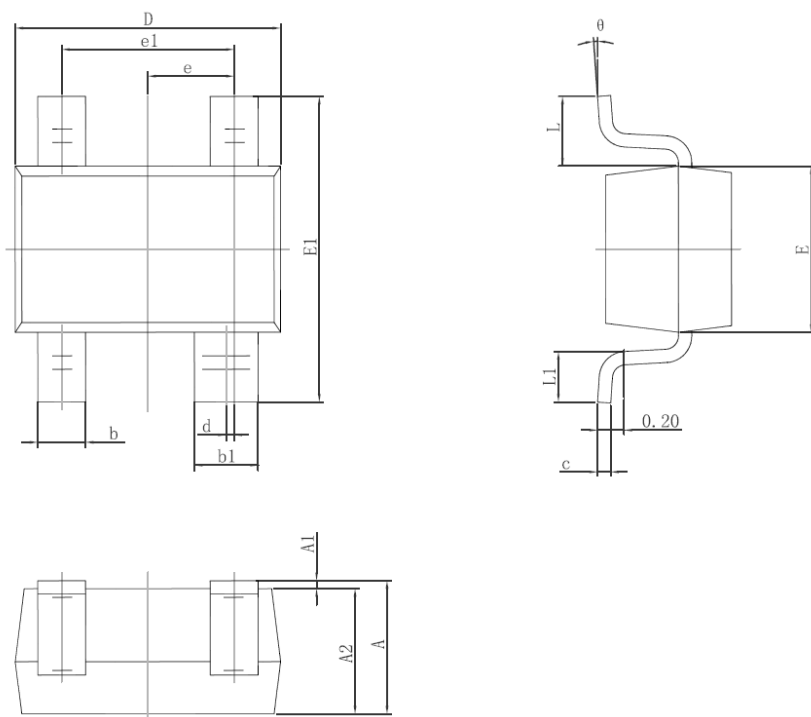
• SOT-23-5



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

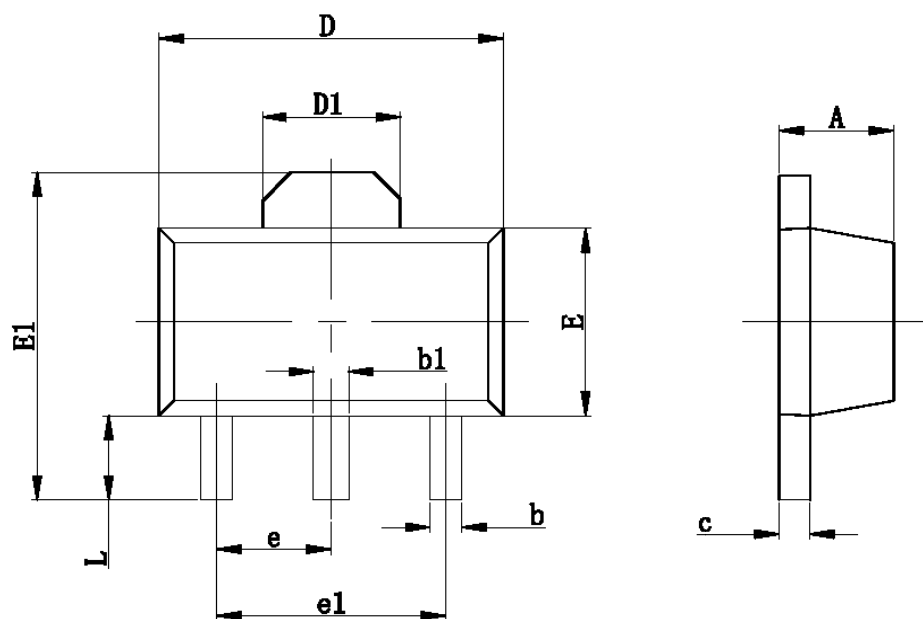


• SOT-343



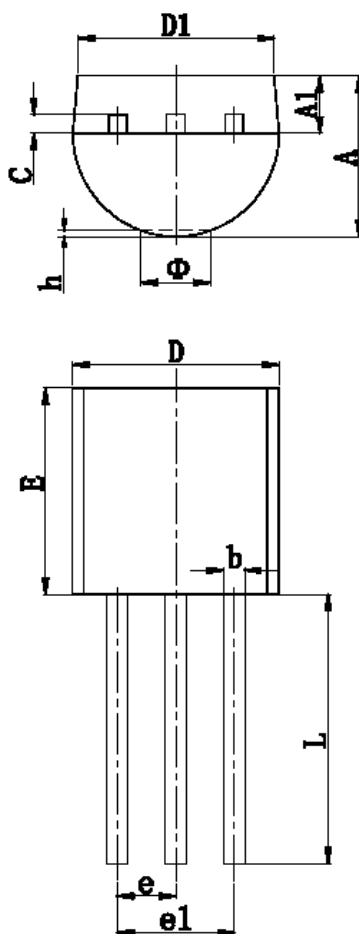
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.250	0.400	0.010	0.016
b1	0.350	0.500	0.014	0.020
c	0.080	0.150	0.003	0.006
d	0.050 TYP.		0.002 TYP.	
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
$\theta$	0°	8°	0°	8°

- SOT-89-3



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060 TYP	
e1	3.000 TYP		0.118 TYP	
L	0.900	1.200	0.035	0.047

• TO-92



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.400	4.700	0.173	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
$\phi$		1.600		0.063
h	0.000	0.380	0.000	0.015

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